

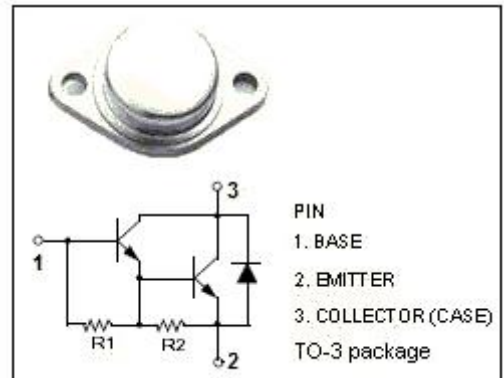
SPTECH Silicon NPN Darlington Power Transistor MJ11016

DESCRIPTION

- Collector-Emitter Breakdown Voltage
: $V_{(BR)CEO} = 120V(\text{Min.})$
- High DC Current Gain-
: $h_{FE} = 1000(\text{Min.})@I_C = 20A$
- Low Collector Saturation Voltage-
: $V_{CE(sat)} = 3.0V(\text{Max.})@I_C = 20A$
- Complement to the PNP MJ11015

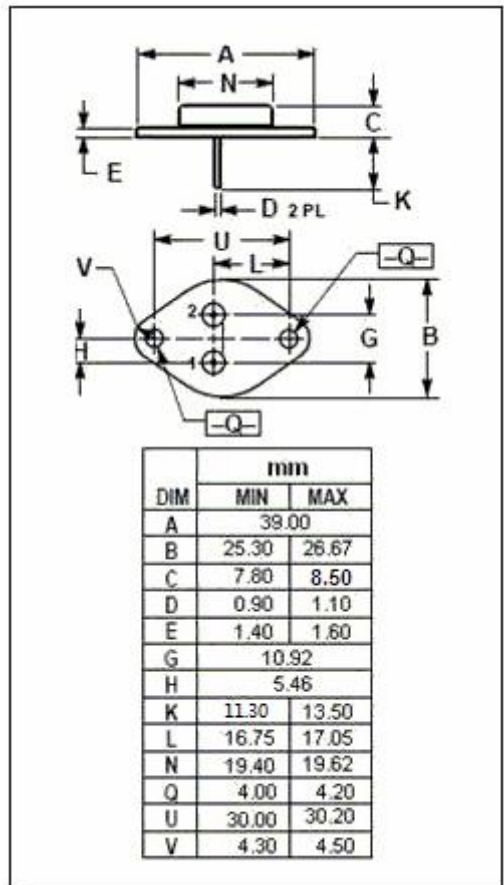
APPLICATIONS

- Designed for use as output devices in complementary general purpose amplifier applications.



ABSOLUTE MAXIMUM RATINGS ($T_a=25^\circ\text{C}$)

SYMBOL	PARAMETER	VALUE	UNIT
V_{CBO}	Collector-Base Voltage	120	V
V_{CEO}	Collector-Emitter Voltage	120	V
V_{EBO}	Emitter-Base Voltage	5	V
I_C	Collector Current-Continuous	30	A
I_B	Base Current-Continuous	1	A
P_C	Collector Power Dissipation @ $T_c=25^\circ\text{C}$	200	W
T_j	Junction Temperature	200	$^\circ\text{C}$
T_{stg}	Storage Temperature Range	-55~+200	$^\circ\text{C}$



THERMAL CHARACTERISTICS

SYMBOL	PARAMETER	MAX	UNIT
$R_{th\ j-c}$	Thermal Resistance, Junction to Case	0.87	$^\circ\text{C/W}$

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ELECTRICAL CHARACTERISTICS

$T_c=25^{\circ}\text{C}$ unless otherwise specified

SYMBOL	PARAMETER	CONDITIONS	MIN	TYP.	MAX	UNIT
$V_{(BR)CEO}$	Collector-Emitter Breakdown Voltage	$I_c= 50\text{mA}; I_B= 0$	120			V
$V_{CE(sat)-1}$	Collector-Emitter Saturation Voltage	$I_c= 20\text{A}; I_B= 0.2\text{A}$			3.0	V
$V_{CE(sat)-2}$	Collector-Emitter Saturation Voltage	$I_c= 30\text{A}; I_B= 0.3\text{A}$			4.0	V
$V_{BE(sat)-1}$	Base-Emitter Saturation Voltage	$I_c= 20\text{A}; I_B= 0.2\text{A}$			3.5	V
$V_{BE(sat)-2}$	Base-Emitter Saturation Voltage	$I_c= 30\text{A}; I_B= 0.3\text{A}$			5.0	V
I_{CBO}	Collector Cutoff Current	$V_{CB}=120\text{V}; I_E=0$ $V_{CB}=120\text{V}; I_E=0; T_c=150^{\circ}\text{C}$			1.0 5.0	mA
I_{CEO}	Collector Cutoff Current	$V_{CE}= 120\text{V}; I_B= 0$			1.0	mA
I_{EBO}	Emitter Cutoff Current	$V_{EB}= 5\text{V}; I_c= 0$			5.0	mA
h_{FE-1}	DC Current Gain	$I_c= 20\text{A}, V_{CE}= 5\text{V}$	1000			
h_{FE-2}	DC Current Gain	$I_c= 30\text{A}, V_{CE}= 5\text{V}$	200			